

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VCXR162600FT

Low-Voltage 18-Bit Universal Bus Transceiver with 3.6-V Tolerant Inputs and Outputs

The TC74VCXR162600FT is a high-performance CMOS 18-bit universal bus transceiver. Designed for use in 1.8-V, 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

It is also designed with overvoltage tolerant inputs and outputs up to 3.6 V.

Data flow in each direction is controlled by output-enable ($\overline{\text{OEAB}}$ and $\overline{\text{OEBA}}$), latch-enable ($\overline{\text{LEAB}}$ and $\overline{\text{LEBA}}$), and clock ($\overline{\text{CKAB}}$ and $\overline{\text{CKBA}}$) inputs. The clock can be controlled by the clock-enable ($\overline{\text{CKENAB}}$ and $\overline{\text{CKENBA}}$) inputs.

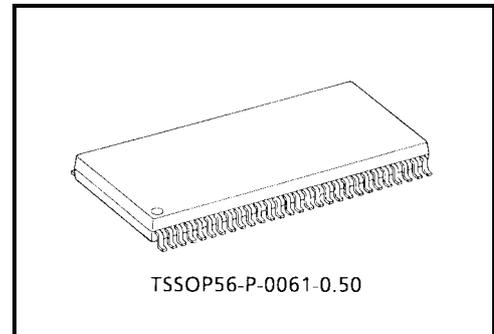
For A-to-B data flow, the device operates in the transparent mode when $\overline{\text{LEAB}}$ is high. When $\overline{\text{LEAB}}$ is low, the A data is latched if $\overline{\text{CKAB}}$ is held at a high or low logic level. If $\overline{\text{LEAB}}$ is low, the A-bus data is stored in the latch/flip-flop on the high-to-low transition of $\overline{\text{CKAB}}$.

Data flow for B to A is similar to that of A to B but uses $\overline{\text{OEBA}}$, $\overline{\text{LEBA}}$, $\overline{\text{CKBA}}$, and $\overline{\text{CKENBA}}$.

When the $\overline{\text{OE}}$ input is high, the outputs are in a high-impedance state. This device is designed to be used with 3-state memory address drivers, etc.

The 26- Ω series resistor helps reducing output overshoot and undershoot without external resistor.

All inputs are equipped with protection circuits against static discharge.



Weight: 0.25 g (typ.)

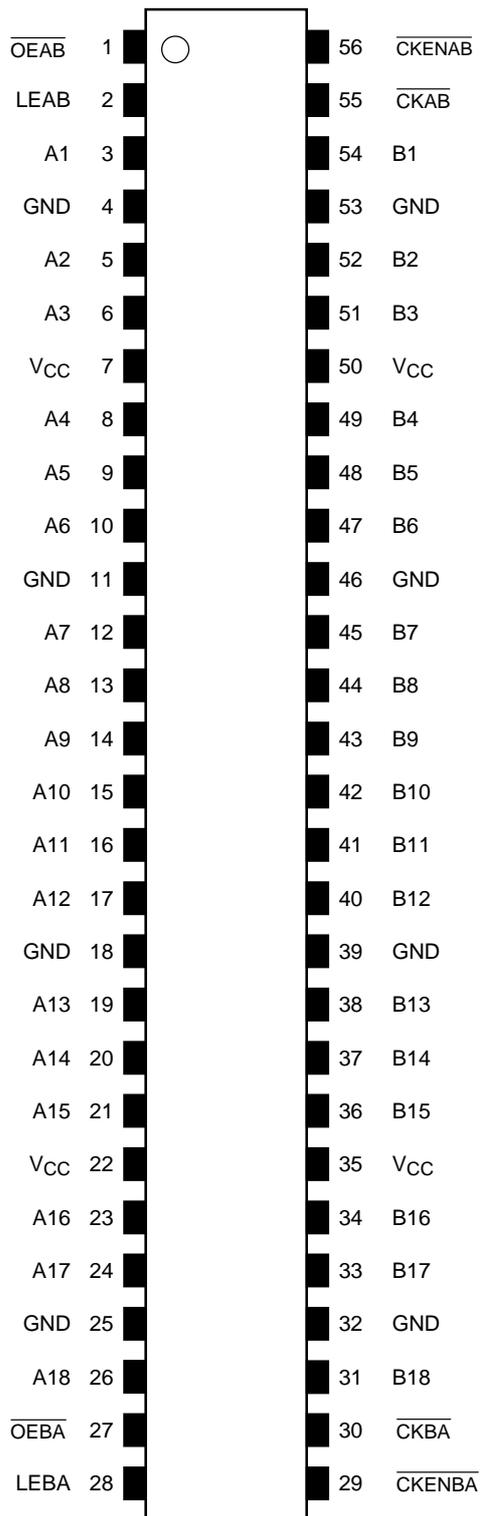
Features

- 26- Ω series resistors on outputs
- Low-voltage operation: $V_{CC} = 1.8$ to 3.6 V
- High-speed operation : $t_{pd} = 3.8$ ns (max) ($V_{CC} = 3.0$ to 3.6 V)
 : $t_{pd} = 5.1$ ns (max) ($V_{CC} = 2.3$ to 2.7 V)
 : $t_{pd} = 9.8$ ns (max) ($V_{CC} = 1.8$ V)
- Output current : $I_{OH}/I_{OL} = \pm 12$ mA (min) ($V_{CC} = 3.0$ V)
 : $I_{OH}/I_{OL} = \pm 8$ mA (min) ($V_{CC} = 2.3$ V)
 : $I_{OH}/I_{OL} = \pm 4$ mA (min) ($V_{CC} = 1.8$ V)
- Latch-up performance: ± 300 mA
- ESD performance: Machine model $> \pm 200$ V
 : Human body model $> \pm 2000$ V
- Package: TSSOP (thin shrink small outline package)
- Bidirectional interface between 2.5 V and 3.3 V signals.
- 3.6-V tolerant function and power-down protection provided on all inputs and outputs

Note 1: Do not apply a signal to any bus pins when it is in the output mode. Damage may result.

All floating (high impedance) bus pins must have their input level fixed by means of pull-up or pull-down resistors.

Pin Assignment (top view)



Truth Table (A bus → B bus)

Inputs					Outputs B
$\overline{\text{CKENAB}}$	$\overline{\text{OEAB}}$	LEAB	$\overline{\text{CKAB}}$	A	
X	H	X	X	X	Z
X	L	H	X	L	L
X	L	H	X	H	H
H	L	L	X	X	B0 (Note 3)
H	L	L	X	X	B0 (Note 3)
L	L	L	\downarrow	L	L
L	L	L	\downarrow	H	H
L	L	L	H	X	B0 (Note 2)
L	L	L	L	X	B0 (Note 2)

Note 2: Output level before the indicated steady-state input conditions were established, provided that $\overline{\text{CKAB}}$ was low or high before LEAB went low.

Note 3: Output level before the indicated steady-state input conditions were established, provided that $\overline{\text{CKENAB}}$ was low or high before LEAB went low.

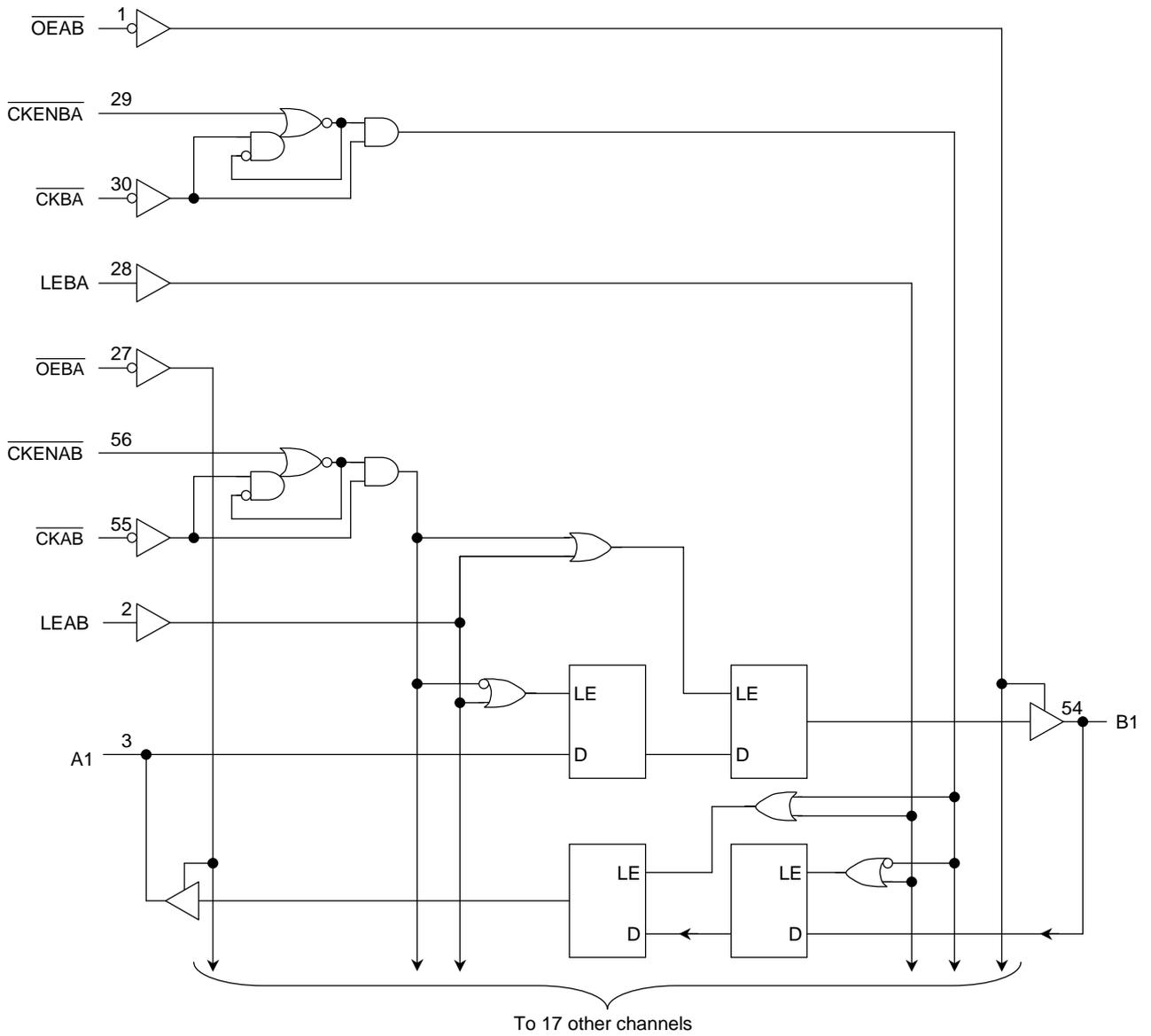
Truth Table (B bus → A bus)

Inputs					Outputs A
$\overline{\text{CKENBA}}$	$\overline{\text{OEBA}}$	LEBA	$\overline{\text{CKBA}}$	B	
X	H	X	X	X	Z
X	L	H	X	L	L
X	L	H	X	H	H
H	L	L	X	X	A0 (Note 5)
H	L	L	X	X	A0 (Note 5)
L	L	L	\downarrow	L	L
L	L	L	\downarrow	H	H
L	L	L	H	X	A0 (Note 4)
L	L	L	L	X	A0 (Note 4)

Note 4: Output level before the indicated steady-state input conditions were established, provided that $\overline{\text{CKBA}}$ was low or high before LEBA went low.

Note 5: Output level before the indicated steady-state input conditions were established, provided that $\overline{\text{CKENBA}}$ was low or high before LEAB went low.

System Diagram



Maximum Ratings

Characteristics	Symbol	Rating	Unit
Power supply voltage	V_{CC}	-0.5 to 4.6	V
DC input voltage (\overline{OEAB} , \overline{OEBA} , \overline{LEAB} , \overline{LEBA} , \overline{CKAB} , $CKBA$, $CKENAB$, $CKENBA$)	V_{IN}	-0.5 to 4.6	V
DC bus I/O voltage	$V_{I/O}$	-0.5 to 4.6 (Note 6)	V
		-0.5 to $V_{CC} + 0.5$ (Note 7)	
Input diode current	I_{IK}	-50	mA
Output diode current	I_{OK}	± 50 (Note 8)	mA
DC output current	I_{OUT}	± 50	mA
Power dissipation	P_D	400	mW
DC V_{CC} /ground current per supply pin	I_{CC}/I_{GND}	± 100	mA
Storage temperature	T_{stg}	-65 to 150	°C

Note 6: OFF state

Note 7: High or low state. I_{OUT} absolute maximum rating must be observed.

Note 8: $V_{OUT} < GND$, $V_{OUT} > V_{CC}$

Recommended Operating Range

Characteristics	Symbol	Rating	Unit
Power supply voltage	V_{CC}	1.8 to 3.6	V
		1.2 to 3.6 (Note 6)	
Input voltage (\overline{OEAB} , \overline{OEBA} , \overline{LEAB} , \overline{LEBA} , \overline{CKAB} , $CKBA$, $CKENAB$, $CKENBA$)	V_{IN}	-0.3 to 3.6	V
Bus I/O voltage	$V_{I/O}$	0 to 3.6 (Note 7)	V
		0 to V_{CC} (Note 8)	
Output current	I_{OH}/I_{OL}	± 12 (Note 9)	mA
		± 8 (Note 10)	
		± 4 (Note 11)	
Operating temperature	T_{opr}	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 10 (Note 12)	ns/V

Note 9: Data retention only

Note 10: OFF state

Note 11: High or low state

Note 12: $V_{CC} = 3.0$ to 3.6 V

Note 13: $V_{CC} = 2.3$ to 2.7 V

Note 14: $V_{CC} = 1.8$ V

Note 15: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V

Electrical Characteristics

DC Characteristics (Ta = -40 to 85°C, 2.7 V < VCC ≤ 3.6 V)

Characteristics		Symbol	Test Condition		VCC (V)	Min	Max	Unit
Input voltage	H-level	V _{IH}	—		2.7 to 3.6	2.0	—	V
	L-level	V _{IL}	—		2.7 to 3.6	—	0.8	
Output voltage	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100 μA	2.7 to 3.6	V _{CC} - 0.2	—	V
				I _{OH} = -6 mA	2.7	2.2	—	
				I _{OH} = -8 mA	3.0	2.4	—	
				I _{OH} = -12 mA	3.0	2.2	—	
	L-level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	2.7 to 3.6	—	0.2	
				I _{OL} = 6 mA	2.7	—	0.4	
				I _{OL} = 8 mA	3.0	—	0.55	
				I _{OL} = 12 mA	3.0	—	0.8	
Input leakage current		I _{IN}	V _{IN} = 0 to 3.6 V		2.7 to 3.6	—	±5.0	μA
3-state output OFF state current		I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 3.6 V		2.7 to 3.6	—	±10.0	μA
Power-off leakage current		I _{OFF}	V _{IN} , V _{OUT} = 0 to 3.6 V		0	—	10.0	μA
Quiescent supply current		I _{CC}	V _{IN} = V _{CC} or GND		2.7 to 3.6	—	20.0	μA
			V _{CC} ≤ (V _{IN} , V _{OUT}) ≤ 3.6 V		2.7 to 3.6	—	±20.0	
Increase in I _{CC} per input		ΔI _{CC}	V _{IH} = V _{CC} - 0.6 V		2.7 to 3.6	—	750	

DC Characteristics (Ta = -40 to 85°C, 2.3 V ≤ VCC ≤ 2.7 V)

Characteristics		Symbol	Test Condition		VCC (V)	Min	Max	Unit
Input voltage	H-level	V _{IH}	—		2.3 to 2.7	1.6	—	V
	L-level	V _{IL}	—		2.3 to 2.7	—	0.7	
Output voltage	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100 μA	2.3 to 2.7	V _{CC} - 0.2	—	V
				I _{OH} = -4 mA	2.3	2.0	—	
				I _{OH} = -6 mA	2.3	1.8	—	
				I _{OH} = -8 mA	2.3	1.7	—	
	L-level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	2.3 to 2.7	—	0.2	
				I _{OL} = 6 mA	2.3	—	0.4	
				I _{OL} = 8 mA	2.3	—	0.6	
Input leakage current		I _{IN}	V _{IN} = 0 to 3.6 V		2.3 to 2.7	—	±5.0	μA
3-state output OFF state current		I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 3.6 V		2.3 to 2.7	—	±10.0	μA
Power-off leakage current		I _{OFF}	V _{IN} , V _{OUT} = 0 to 3.6 V		0	—	10.0	μA
Quiescent supply current		I _{CC}	V _{IN} = V _{CC} or GND		2.3 to 2.7	—	20.0	μA
			V _{CC} ≤ (V _{IN} , V _{OUT}) ≤ 3.6 V		2.3 to 2.7	—	±20.0	

DC Characteristics (Ta = -40 to 85°C, 1.8 V ≤ VCC < 2.3 V)

Characteristics		Symbol	Test Condition		VCC (V)	Min	Max	Unit
Input voltage	H-level	V _{IH}	—		1.8 to 2.3	0.7 × V _{CC}	—	V
	L-level	V _{IL}	—		1.8 to 2.3	—	0.2 × V _{CC}	
Output voltage	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100 μA	1.8	V _{CC} - 0.2	—	V
				I _{OH} = -4 mA	1.8	1.4	—	
	L-level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	1.8	—	0.2	
				I _{OL} = 4 mA	1.8	—	0.3	
Input leakage current		I _{IN}	V _{IN} = 0 to 3.6 V		1.8	—	±5.0	μA
3-state output OFF state current		I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 3.6 V		1.8	—	±10.0	μA
Power-off leakage current		I _{OFF}	V _{IN} , V _{OUT} = 0 to 3.6 V		0	—	10.0	μA
Quiescent supply current		I _{CC}	V _{IN} = V _{CC} or GND		1.8	—	20.0	μA
			V _{CC} ≤ (V _{IN} , V _{OUT}) ≤ 3.6 V		1.8	—	±20.0	

AC Characteristics (Ta = -40 to 85°C, input: tr = tf = 2.0 ns, CL = 30 pF, RL = 500 Ω)

Characteristics	Symbol	Test Condition	VCC (V)	Min	Max	Unit
Maximum clock frequency	f _{max}	Figure 1, Figure 3	1.8	100	—	MHz
			2.5 ± 0.2	200	—	
			3.3 ± 0.3	250	—	
Propagation delay time (An, Bn-Bn, An)	t _{pLH} t _{pHL}	Figure 1, Figure 2	1.8	1.5	9.8	ns
			2.5 ± 0.2	0.8	5.1	
			3.3 ± 0.3	0.6	3.8	
Propagation delay time ($\overline{\text{CKAB}}$, $\overline{\text{CKBA}}$ -Bn, An)	t _{pLH} t _{pHL}	Figure 1, Figure 3	1.8	1.5	9.8	ns
			2.5 ± 0.2	0.8	6.4	
			3.3 ± 0.3	0.6	4.4	
Propagation delay time (LEAB, LEBA-Bn, An)	t _{pLH} t _{pHL}	Figure 1, Figure 4	1.8	1.5	9.8	ns
			2.5 ± 0.2	0.8	5.8	
			3.3 ± 0.3	0.6	4.4	
Output enable time ($\overline{\text{OEAB}}$, $\overline{\text{OEBA}}$ -Bn, An)	t _{pZL} t _{pZH}	Figure 1, Figure 6	1.8	1.5	9.8	ns
			2.5 ± 0.2	0.8	5.9	
			3.3 ± 0.3	0.6	4.3	
Output disable time ($\overline{\text{OEAB}}$, $\overline{\text{OEBA}}$ -Bn, An)	t _{pLZ} t _{pHZ}	Figure 1, Figure 6	1.8	1.5	8.8	ns
			2.5 ± 0.2	0.8	4.9	
			3.3 ± 0.3	0.6	4.3	
Minimum pulse width	t _W (H) t _W (L)	Figure 1, Figure 3, Figure 4	1.8	4.0	—	ns
			2.5 ± 0.2	1.5	—	
			3.3 ± 0.3	1.5	—	
Minimum setup time	t _s	Figure 1, Figure 3, Figure 4, Figure 5	1.8	2.5	—	ns
			2.5 ± 0.2	1.5	—	
			3.3 ± 0.3	1.5	—	
Minimum hold time	t _h	Figure 1, Figure 3, Figure 4, Figure 5	1.8	2.0	—	ns
			2.5 ± 0.2	1.5	—	
			3.3 ± 0.3	1.0	—	
Output to output skew	t _{osLH} t _{osHL}	(Note 16)	1.8	—	0.5	ns
			2.5 ± 0.2	—	0.5	
			3.3 ± 0.3	—	0.5	

For C_L = 50 pF, add approximately 300 ps to the AC maximum specification.

Note 16: Parameter guaranteed by design.

$$(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$$

Dynamic Switching Characteristics

($T_a = 25^\circ\text{C}$, input: $t_r = t_f = 2.0 \text{ ns}$, $C_L = 30 \text{ pF}$, $R_L = 500 \Omega$)

Characteristics	Symbol	Test Condition		Typ.	Unit	
			V _{CC} (V)			
Quiet output maximum dynamic V _{OL}	V _{OLP}	V _{IH} = 1.8 V, V _{IL} = 0 V	(Note 17)	1.8	0.15	V
		V _{IH} = 2.5 V, V _{IL} = 0 V	(Note 17)	2.5	0.25	
		V _{IH} = 3.3 V, V _{IL} = 0 V	(Note 17)	3.3	0.35	
Quiet output minimum dynamic V _{OL}	V _{OLV}	V _{IH} = 1.8 V, V _{IL} = 0 V	(Note 17)	1.8	-0.15	V
		V _{IH} = 2.5 V, V _{IL} = 0 V	(Note 17)	2.5	-0.25	
		V _{IH} = 3.3 V, V _{IL} = 0 V	(Note 17)	3.3	-0.35	
Quiet output minimum dynamic V _{OH}	V _{OHV}	V _{IH} = 1.8 V, V _{IL} = 0 V	(Note 17)	1.8	1.55	V
		V _{IH} = 2.5 V, V _{IL} = 0 V	(Note 17)	2.5	2.05	
		V _{IH} = 3.3 V, V _{IL} = 0 V	(Note 17)	3.3	2.65	

Note 17: Parameter guaranteed by design.

Capacitive Characteristics ($T_a = 25^\circ\text{C}$)

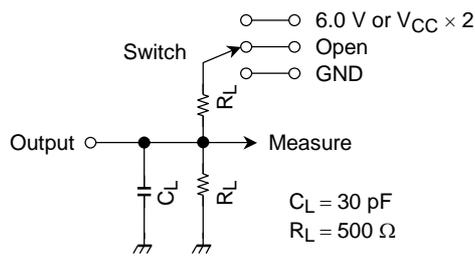
Characteristics	Symbol	Test Condition		Typ.	Unit	
			V _{CC} (V)			
Input capacitance	C _{IN}	—		1.8, 2.5, 3.3	6	pF
Bus I/O capacitance	C _{I/O}	—		1.8, 2.5, 3.3	7	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz	(Note 18)	1.8, 2.5, 3.3	20	pF

Note 18: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC(\text{opr})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/18 \text{ (per bit)}$$

AC Test Circuit



Parameter	Switch
t_{pLH}, t_{pHL}	Open
t_{pLZ}, t_{pZL}	6.0 V $V_{CC} \times 2$ @ $V_{CC} = 3.3 \pm 0.3 \text{ V}$ @ $V_{CC} = 2.5 \pm 0.2 \text{ V}$ @ $V_{CC} = 1.8 \text{ V}$
t_{pHZ}, t_{pZH}	GND

Figure 1

AC Waveform

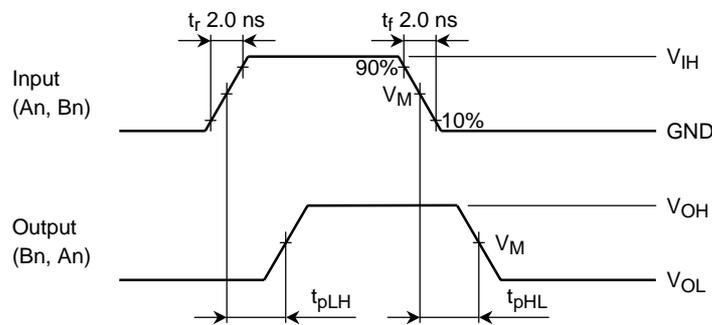


Figure 2 t_{pLH}, t_{pHL}

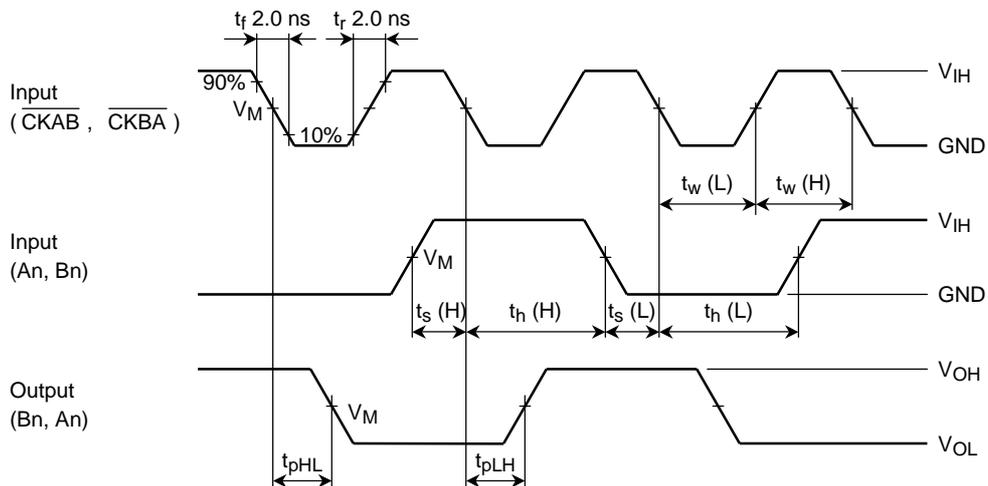


Figure 3 $t_{pLH}, t_{pHL}, t_w, t_s, t_h$

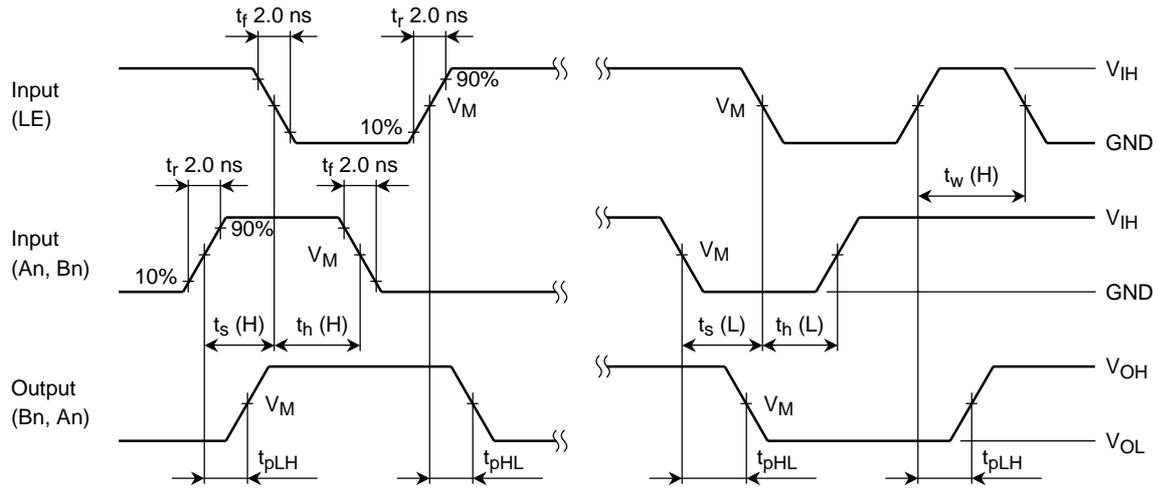


Figure 4 t_{pLH} , t_{pHL} , t_w , t_s , t_h

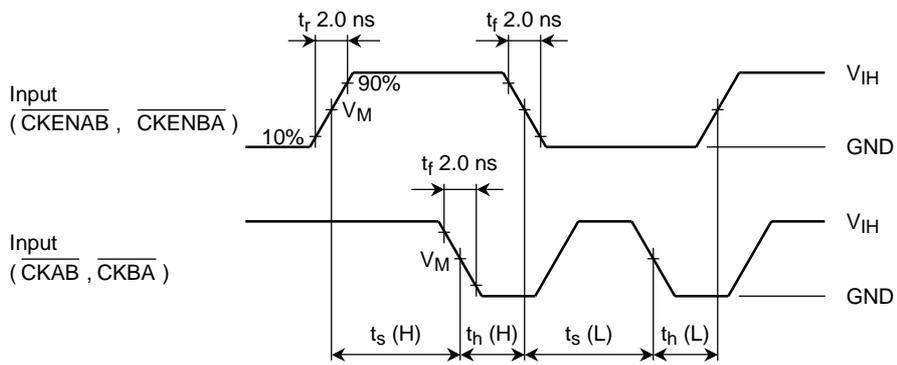


Figure 5 t_s , t_h

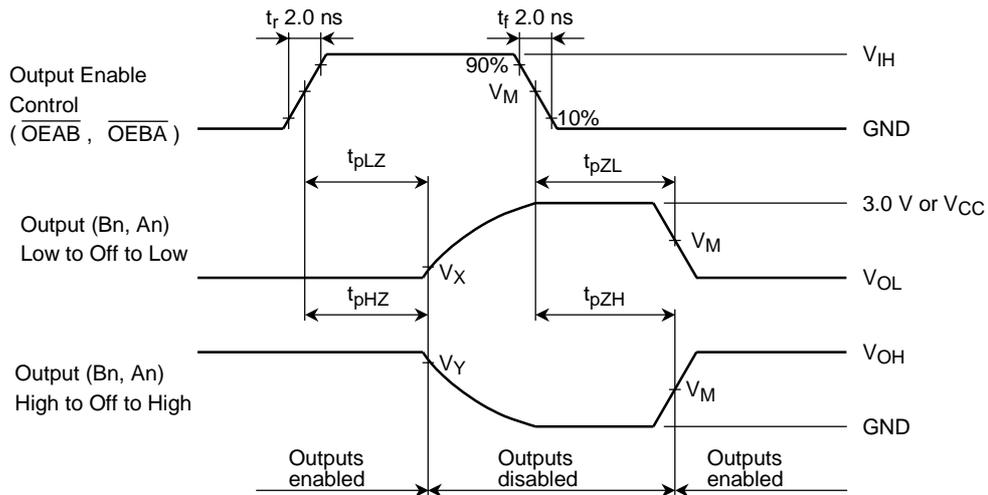


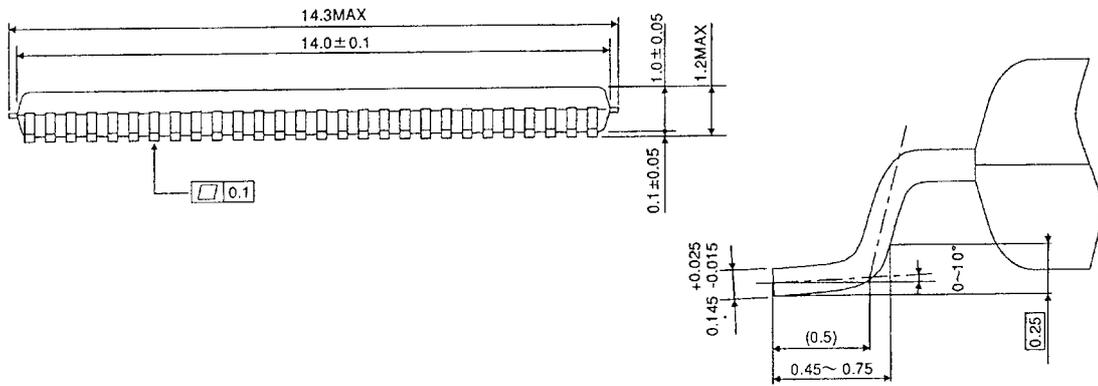
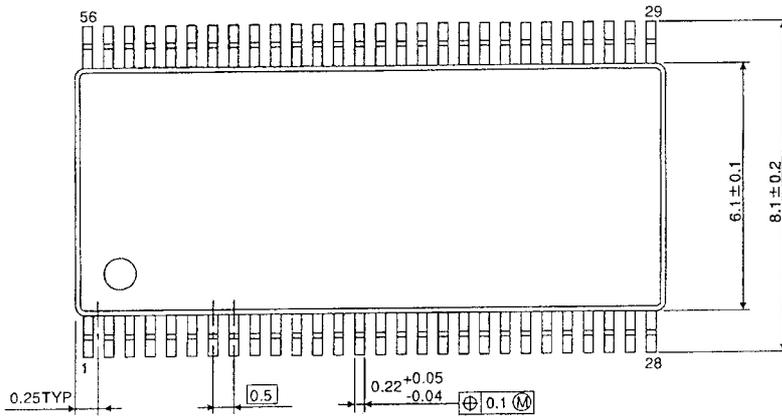
Figure 6 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

Symbol	V_{CC}		
	$3.3 \pm 0.3 \text{ V}$	$2.5 \pm 0.2 \text{ V}$	1.8 V
V_{IH}	2.7 V	V_{CC}	V_{CC}
V_M	1.5 V	$V_{CC}/2$	$V_{CC}/2$
V_X	$V_{OL} + 0.3 \text{ V}$	$V_{OL} + 0.15 \text{ V}$	$V_{OL} + 0.15 \text{ V}$
V_Y	$V_{OH} - 0.3 \text{ V}$	$V_{OH} - 0.15 \text{ V}$	$V_{OH} - 0.15 \text{ V}$

Package Dimensions

TSSOP56-P-0061-0.50

Unit : mm



Weight: 0.25 g (typ.)

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